

I/O module for 2 tri-axis MEMS sensors

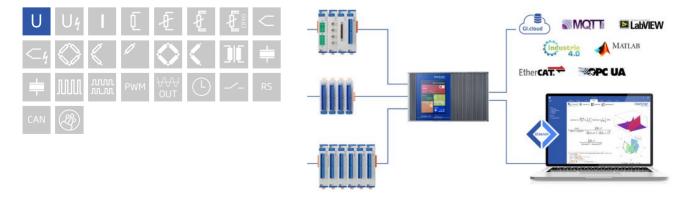
Q.raxx XL is a new addition to the Q.series product family - the ideal 19" rackmount DAQ solution for applications that require high channel density and custom sensor terminations. Q.raxx XL DAQ systems can utilize an integrated, high-performance controller for communication, control, and data logging purposes. With a controller, multiple Q.raxx XL systems can be synchronized to each other allowing for efficient DAQ distribution with low jitter and gradual expansion up to thousands of channels.

- High Density up to 13 I/O modules per Q.raxx 3U chassis with up to 16 channels per I/O module
- User Friendly front panel indicators for module status, power, and input range error
- Fully Customizable multiple front panel termination options available
- Maximum Flexibility parallel communication available in TCP/IP, CAN, PROFIBUS, Modbus, and EtherCAT
- Gantner's Quality Standard integrated filtering, galvanic isolation & signal/sensor conditioning per channel



Key Features

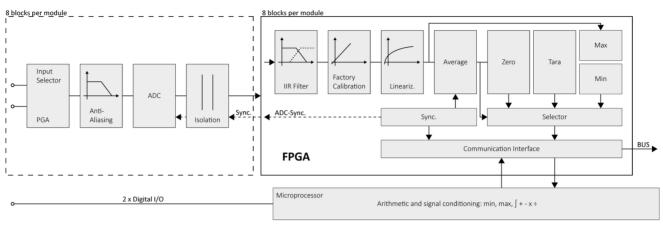
- I/O module for 2 tri-axis MEMS sensors
 2 DSUB9 input sockets
 Sensor supply galvanic isolated
- 6+2 Analog input channels
 Al1,Al2,Al3 differential /single-ended switchable in groups
 Al5,Al6,Al7 differential /single-ended switchable in groups
 Al4,Al8 single-ended (e.g. for temperature input/compensation)
- High-accuracy digitization
 24-bit ADC, 20 kHz sample rate per channel
- Signal conditioning linearization, filtering, average, scaling, min/max, RMS, arithmetic, alarm
- 3-Way galvanic isolation
 500 VDC channel to channel, channel to power supply, and channel to bus





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Block diagram



Technical Data

Pin assignment DSUB 9

Pin		
1	Power	Supply +15 V
2	Return	Supply GND
З	X +	X-axis +
4	Υ +	Y-axis +
5	Z +	Z-axis +
6	X -	X-axis -
7	Y -	Y-axis -
8	Z -	Z-axis -
9	Temp	temperature

Analog Input

Channels	6 + 2 AI1, AI2, AI3 differential / single ended, switchable in groups AI5, AI6, AI7 differential / single ended, switchable in groups AI4, AI8 single ended (e.g. for temperature input/compensation)
Accuracy	0.01 % typical
	0.025 % in controlled environment ¹
	0.05 % in industrial area ²
Linearity error	0.01 % typical full-scale
Repeatability	0.003 % typical (within 24 hrs)
Isolation voltage	500 VDC channel to channel, to power supply, and channel to bus 3

¹ according to EN 61326 2006: appendix B

² according to EN 61326 2006: appendix A

 $^{\rm 3}\,$ noise pulses up to 1000 VDC, continuous up to 250 VDC



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Voltage Measurement

Input range	±10 VDC	
Margin of error	±2 mV	
Resolution	1.5 μV	
Long-term stability	<50 µV / 24 hrs	< 200 µV / 8000 hrs
Temperature drift	<200 µV / 10 K Offset drift	<100 ppm / 10 K Gain drift
Signal-to-noise ratio	>100 dB at 100 Hz	>120 dB at 1 Hz
Input impedance	>1 MΩ	
Overvoltage protection	± 200 V	
Signal-to-noise ratio Input impedance	>100 dB at 100 Hz > 1 MΩ	

Analog-to-Digital Conversion

Resolution	24-bit
Sample rate	20 kHz per channel
Modulation method	sigma-delta
Anti-aliasing filter	2 kHz, 3rd order
Digital filters	Infinite impulse response (IIR), low-pass, high-pass, band-pass, Butterworth or Bessel (2nd, 4th, 6th or 8th order), frequency range 0.1 Hz to 1 kHz (adjustable via software)
Averaging	configurable or automatic according to the user-defined data rate

Sensor excitation

Channels	2
Voltage	15 V
Current	max. 40 mA (short circuit proof)
Accuracy	< 3 %
Load regulation	< 0.1 %
Noise	1.2 mV (RMS)

Communication Interface

Protocols	proprietary Localbus (115200 bps to 48 Mbps, latency <100 ns) ASCII (19200 bps to 115200 bps) Modbus RTU
Data format	8E1
Electrical standard	ANSI/TIA/EIA-485-A, 2-wire

Input Power

Input voltage	10 to 30 VDC, overvoltage and overcurrent protection
Power consumption	3.5 W (approx.)
Input voltage influence	<0.001 % / V

Environmental Specifications

Electromagnetic compatibility (EMC)	according to IEC 61000-4 and EN 55011	
Operating temperature	-20°C to +60°C	
Storage temperature	-40°C to +85°C	
Relative humidity	5 - 95 % at 50°C (non-condensing)	



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Remarks

Validity of all listed specifications are subject to a warm-up period of at least 45 minutes	
Specifications subject to change without notice	

Mechanical information

Material	Aluminum
Measurements (W x H x D)	30x 128 x 120mm
Weight	approx. 200 g

Ordering Information

Article number 586835

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